



**DMN2022UNS** 

**D2** 

S2

#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
	10.8m $\Omega$ @ V <sub>GS</sub> = 4.5V	10.7A
20V	14.5m $\Omega$ @ V <sub>GS</sub> = 2.5V	9.3A
	17.0mΩ @ $V_{GS}$ = 1.8V	8.6A

#### Description

This new generation MOSFET has been designed to minimize the onstate resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

#### **Applications**

- **Power Management Functions**
- Load Switch

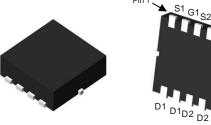
#### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

#### **Features**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Complementary Pair MOSFET
- ESD Protected Up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

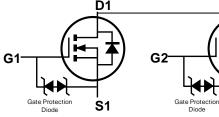
#### **Mechanical Data**

- Case: POWERDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.0065 grams (Approximate)



Top View





Internal Schematic

### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2022UNS-7	POWERDI <sup>®</sup> 3333-8	2000/Tape & Reel
DMN2022UNS-13	POWERDI <sup>®</sup> 3333-8	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

Bottom View

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## Marking Information



S23 = Product Type Marking Code  $\underline{YY}WW = Date Code Marking$ YY = Last Digit of Year (ex: 15 = 2015) WW = Week Code (01 to 53)

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POWERDI<sup>®</sup>3333-8



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V <sub>DSS</sub>	20	V		
Gate-Source Voltage	V <sub>GSS</sub>	±10	V		
Continuous Drain Current (Nate C) // 10//	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	10.7 8.6	A
Continuous Drain Current (Note 6) $V_{GS} = 10V$	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	13.9 11.1	А
Maximum Body Diode Forward Current (Note 6)	Is	2	A		
Pulsed Drain Current (10µs pulse, Duty cycle = 1%)	I <sub>DM</sub>	60	A		
Avalanche Current (Note 7) L = 0.1mH			IAS	17.1	A
Avalanche Energy (Note 7) L = 0.1mH			E <sub>AS</sub>	14.7	mJ

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)		PD	1.2	W
Thermal Pagistance, Junction to Ambient (Note 5)	Steady State	D	107	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ extsf{ heta}JA}$	64	
Total Power Dissipation (Note 6)		PD	1.9	W
Thermal Desistance, Junction to Ambient (Note 6)	Steady State	0	67	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ extsf{ heta}JA}$	40	
Operating and Storage Temperature Range	T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C	

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

					•		
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)					-		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	_	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	IDSS		—	1	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	—	±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.4	—	1	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
		—	9.0	10.8		$V_{GS} = 4.5V, I_D = 4A$	
		—	9.2	11.2		$V_{GS} = 4.0V, I_D = 4A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	9.8	13.0	mΩ	$V_{GS} = 3.1V, I_D = 4A$	
		—	10.5	14.5		$V_{GS} = 2.5V, I_D = 4A$	
		_	13.9	17.0		$V_{GS} = 1.8V, I_D = 4A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.1	V	$V_{GS} = 0V, I_S = 5A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	1870		pF		
Output Capacitance	C <sub>oss</sub>	_	320	_	pF	$V_{DS} = 10V, V_{GS} = 0V,$ - f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>		160	—	pF		
Gate Resistance	Rg	_	96	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg		20.3	—	nC		
Gate-Source Charge	Q <sub>gs</sub>	_	2.8	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$	
Gate-Drain Charge	Q <sub>qd</sub>	_	3.6	_	nC	$I_{\rm D} = 6.5 {\rm A}$	
Turn-On Delay Time	t <sub>D(ON)</sub>		62	_	ns		
Turn-On Rise Time	t <sub>R</sub>		101	_	ns	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V,	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	596	_	ns	$R_G = 6\Omega, R_L = 1.0\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	_	224	—	ns	7	
Reverse Recovery Time	t <sub>RR</sub>	_	150	_	ns	I <sub>F</sub> = 4A, di/dt = 100A/µs	
Reverse Recovery Charge	Q <sub>RR</sub>	_	135	_	nC	I <sub>F</sub> = 4A, di/dt = 100A/µs	

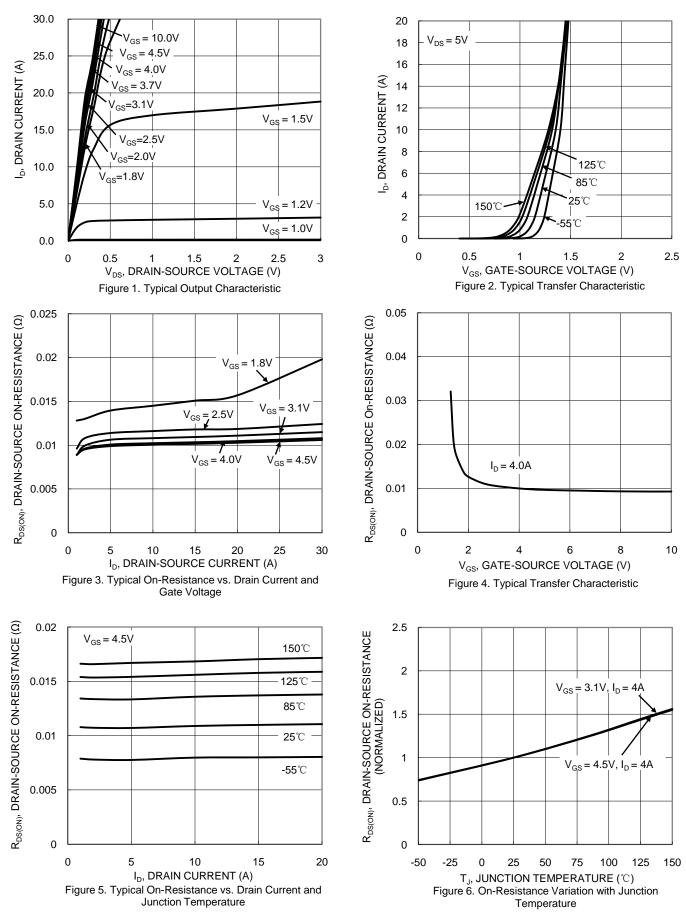
Notes:

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

bevice mounted on FR-4 PC board, with minimum recommended pad layout, single study.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
I<sub>AS</sub> and E<sub>AS</sub> rating are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.

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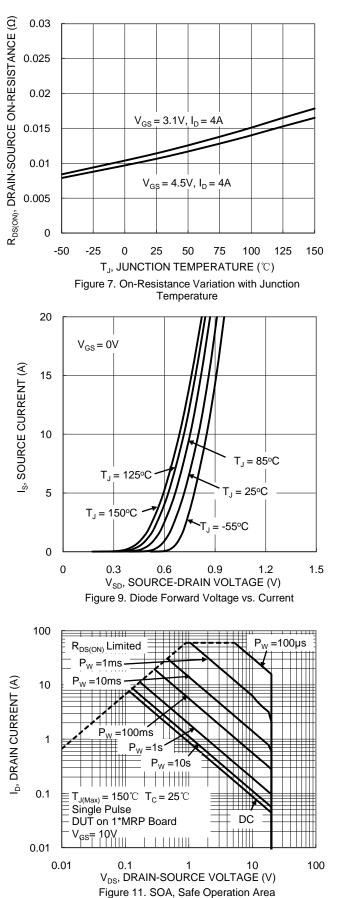


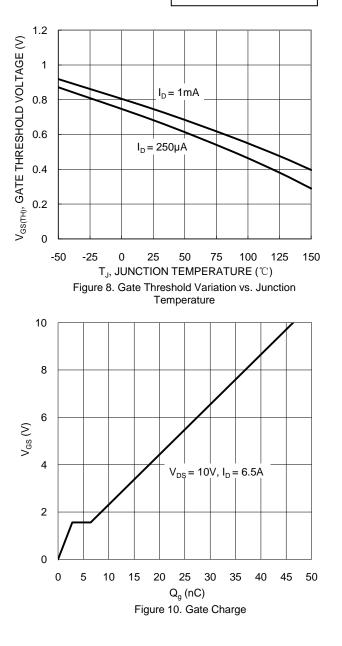
NEW PRODUCT

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3 of 7 www.diodes.com November 2015 © Diodes Incorporated



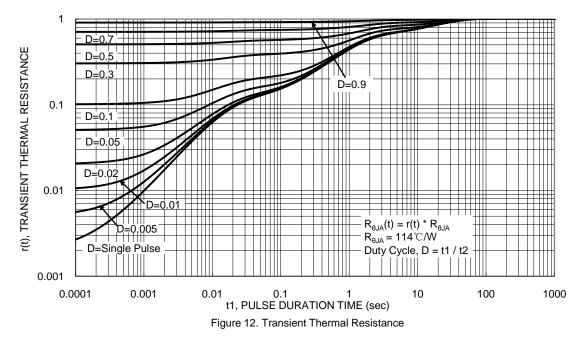




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4 of 7 www.diodes.com



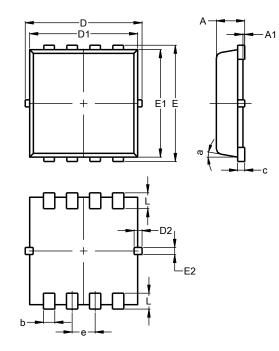




## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### POWERDI<sup>®</sup>3333-8 (Type UXB)

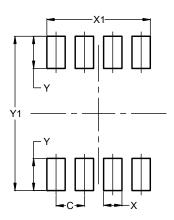


POWERDI <sup>®</sup> 3333-8						
	(Type UXB)					
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	-			
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	0.10	0.35	0.23			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	0.10	0.30	0.20			
е	_	_	0.65			
L	0.35	0.55	0.45			
а	0°	12°	10°			
All I	All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

POWERDI<sup>®</sup>3333-8 (Type UXB)



Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	2.370			
Y	0.730			
Y1	3.500			



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